

Product data sheet



1.1 General description

The BB149A is a variable capacitance diode, fabricated in planar technology and encapsulated in the SOD323 very small SMD plastic package. The excellent matching performance is achieved by gliding matching and a Direct Matching Assembly (DMA) procedure.

1.2 Features

- Excellent linearity
- Excellent matching to 2 % DMA
- Very small SMD plastic package
- Arr C_{d(28V)}: 2.1 pF; C_{d(1V)} to C_{d(28V)} ratio: 9
- Low series resistance.

1.3 Applications

- Electronic tuning in UHF television tuners
- Voltage Controlled Oscillators (VCO).

2. **Pinning information**

Table 1: **Pinning**

Pin	Description	Simplified outline [1]	Symbol
1	cathode		Ш
2	anode	1 2	sym008

^[1] The marking bar indicates the cathode.

Ordering information 3.

Table 2: **Ordering information**

Type number	Package				
	Name	Description	Version		
BB149A	SC-76	plastic surface mounted package; 2 leads	SOD323		



UHF variable capacitance diode

4. Marking

Table 3: Marking

Type number	Marking code
BB149A	PL

5. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	30	V
V_{RM}	peak reverse voltage	in series with a 10 $k\Omega$ resistor	-	35	V
I _F	forward current		-	20	mA
T _{stg}	storage temperature		-55	+150	°C
T _j	junction temperature		-55	+125	°C

6. Characteristics

Table 5: Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	N	1in	Тур	Max	Unit
I _R	reverse current	V _R = 30 V					
		see Figure 2	-		-	10	nA
		T _j = 85 °C; see Figure 2	-		-	200	nA
r _s	diode series resistance	f = 470 MHz	[1] -		0.6	0.75	Ω
C_d	diode	f = 1 MHz; see Figure 1 and 3					
	capacitance	V _R = 1 V	1	8.22	-	21.26	pF
		V _R = 28 V	1	.951	2.1	2.225	pF
$\frac{C_{d(1V)}}{C_{d(2V)}}$	capacitance ratio	f = 1 MHz	-		1.27	-	
$\frac{C_{d(1V)}}{C_{d(28V)}}$	capacitance ratio	f = 1 MHz	8	.45	9	10.9	
$\frac{C_{d(25V)}}{C_{d(28V)}}$	capacitance ratio	f = 1 MHz	-		1.05	-	
$\frac{\Delta C_d}{C_d}$	capacitance matching	$V_R = 1 \text{ V to } 28 \text{ V; in a}$ sequence of 10 diodes (gliding)	-		-	2	%

^[1] V_R is the value at which $C_d = 9 pF$

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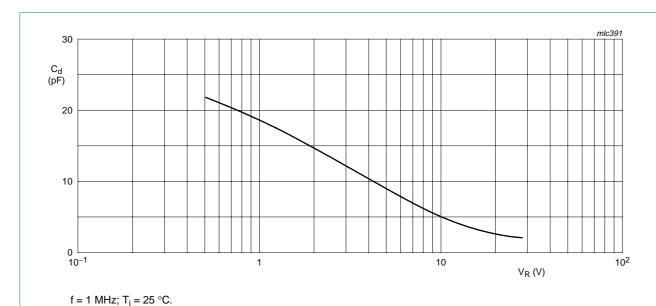


Fig 1. Diode capacitance as a function of reverse voltage; typical values.

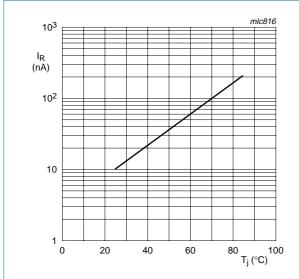
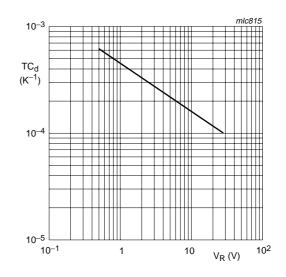


Fig 2. Reverse current as a function of junction temperature; maximum values.



 T_j = 0 °C to 85 °C.

Fig 3. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.



7. Package outline

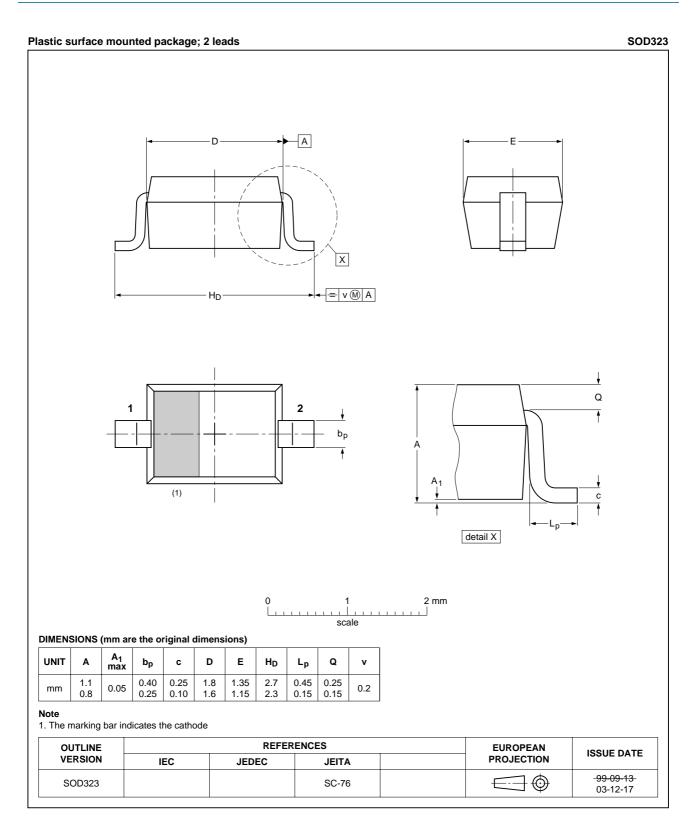


Fig 4. Package outline SOD323 (SC-76).

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8. Revision history

Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes	
BB149A_3	20041005	Product data sheet	-	9397 750 13826	BB149A_2	
Modifications: • The format of this data sheet has been redesigned to comply with the new information standard of Philips Semiconductors				v presentation and		
	 <u>Table 5 "Characteristics"</u>: ΔC_d/C_d conditions changed from sequence of 15 diodes to sequence of 10 diodes 					
	• Table 5 "C	haracteristics": added typ	oical value of 2.1 pF	for C _{d(28V)}		
	 Table 5 "C 	haracteristics": added typ	oical value of 9 for C	$C_{d(1V)}$ to $C_{d(28V)}$ ratio).	
BB149A_2	20040301	Product specification	-	9397 750 12654	BB149A_1	
BB149A_1	19971217	Product specification	-	9397 750 02653	-	

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Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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